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CONTENTS

Invited Papers

- LET'S CONSIDER MOORE'S LAW IN ITS ENTIRETY, **Gh. Stefan**, Univ. "Politehnica" of Bucharest, Romania 3
- THz SPECTROSCOPY BY NARROW SPECTRAL EMISSION OF QUANTUM CASCADE LASERS FOR MEDICAL APPLICATIONS, **H.L. Hartnagel¹, V.P. Sirkeli², P. Acedo^{3,4}**, ¹Technische Univ. Darmstadt, Germany, ²Moldova State Univ., Moldova, ³Univ. Carlos III de Madrid, ⁴Inst. de Investigacion Sanitaria de la Fundacion Jimenez Diaz, Madrid, Spain 11

Nanoscience & Nanoengineering 1

- PHOTOLUMINESCENCE STUDY OF Si_{1-x}Ge_x NANOPARTICLES IN VARIOUS OXIDE MATRICES, **M.T. Sultan¹, J.T. Gudmundsson^{1,2}, A. Manolescu³, M.L. Ciurea^{4,5}, H.G. Svavarsson³, S. Ingvansson¹**, ¹Univ. of Iceland, Reykjavik, Iceland, ²KTH-Royal Inst. of Technology, Sweden, ³Reykjavik Univ., Iceland, ⁴National Inst. of Materials Physics, ⁵Academy of Romanian Scientists, Bucharest, Romania..... 21
- INNOVATIVE IDEAS IN THE DESIGN, RE-USE AND RE-FABRICATION OF RARE EARTH-BASED MATERIALS IN THE CONTEXT OF MICROELECTRONICS AND RENEWABLE ENERGY, **R.-R. Piticescu¹, M. Prakasam², O. Jay³, A.E. Slobozeanu¹, M. Burada¹**, ¹National R&D Inst. for Nonferrous and Rare Metals-IMNR, Romania, ²CNRS-ICMCB Bordeaux, France, ³Faddtory Srl, Belgium..... 25

Nanoscience & Nanoengineering 2

- TiO₂ - rGO COMPOSITE THIN FILMS IN VIS-ACTIVE PHOTOCATALYSIS, **I. Tismanar, A.C. Obreja*, O. Buiu*, A. Duta**, "Transilvania" Univ. of Brasov, *IMT Bucharest, Romania..... 31
- FACILE FORMATION OF SELF-ASSEMBLED Ga DROPLETS ON GaAs (001) SUBSTRATE **M.T. Sultan, H.Ö. Arnason*, S. Ingvansson, U.B. Arnalds, H.G. Svavarsson*, A. Manolescu*, A. Valfells***, Univ. of Iceland, Reykjavik, *Reykjavik Univ., Iceland..... 35
- WAFER-LEVEL FABRICATION OF NANOCONES STRUCTURES BY UV-NANOIMPRINT AND CRYOGENIC DEEP REACTIVE ION PROCESS, **O. Rasoga¹, C. Thanner², O. Semenova², A.M. Avram³, L.-I. Jinga⁴**, ¹National Inst. of Materials Physics, Romania, ²EV Group, Austria, ³IMT Bucharest, ⁴National Inst. for Lasers, Plasma and Radiation Physics, Romania..... 39

Microwave & Millimeter Wave Circuits & Systems

ON THE ANALYSIS OF THE RECTANGULAR DIELECTRIC WAVEGUIDE, BY USING THE GENERALIZED TELEGRAPHIST'S EQUATIONS BASED METHOD, S. Simion , Electronics and Communications Dept., MTA – Bucharest, Romania.....	45
RFID TAG WITH ELECTROMAGNETIC WAVE POLARIZATION DIVERSITY, D. Neculoiu ^{1,2} , A.-C. Bunea ¹ , ¹ IMT Bucharest, ² Univ. "Politehnica" of Bucharest, Romania.....	49
NUMERICAL MODELLING OF 180° HYBRID RING COUPLERS OPERATING IN THE GSM 1800 BAND, V. Ionescu , "Ovidius" Univ. of Constanta, Romania.....	53

Sensors & Micro-Optics

DESIGN AND SYNTHESIS OF ZnO-n/NiO-p MICROSTRUCTURES FOR ROOM-TEMPERATURE FORMALDEHYDE SENSING, M. Chelu , P. Chesler , M. Anastasescu , C. Hornoiu , D. Mitrea , C. Brasoveanu* , C. Moldovan* , M. Gartner , Inst. of Physical Chemistry "Ilie Murgulescu" of the Romanian Academy, *IMT Bucharest, Romania.....	N/A
COMPARISON OF PERFORMANCE OF MICROBIAL FUEL CELLS BASED ON RIVER SEDIMENT AND ACID MINE DRAINAGE SEDIMENT, D. Randjelović , K. Joksimović , A. Žerađanin , B. Popović , P. Poljak , V. Beškosi* , Inst. of Chemistry, Technology and Metallurgy, Univ. of Belgrade, *Faculty of Chemistry, Univ. of Belgrade, Republic of Serbia.....	N/A
NOVEL ScAlN/Si SAW-TYPE DEVICES TARGETING SURFACE ACOUSTIC WAVE/SPIN WAVE COUPLING, A. Nicoloiu ¹ , C. Nastase ¹ , I. Zdru ¹ , D. Vasilache ¹ , G. Boldeiu ^{1,2} , M. C. Ciornei ¹ , A. Dinescu ¹ , A. Müller ¹ , ¹ IMT Bucharest, ² Univ. "Politehnica" of Bucharest, Romania....	67
UV IMPRINTING PROCESSES FOR FABRICATION OF MICRO OPTICAL COMPONENTS C. Thanner , J. Peter , R. Breyer , M. Begel , EV Group, St. Florian am Inn, Austria.....	71
DESIGN AND FABRICATION OF FRESNEL LENSES ARRAY, M. Kusko , A. Avram , IMT Bucharest, Romania	75

Modelling

MODELING THE TEMPERATURE-DEPENDENT REVERSE BREAKDOWN BEHAVIOR OF GaAs PIN DIODES, P. Scharf , F.A. Velarde Gonzalez , A. Lange , M. Dietrich* , V. Dudek* , Fraunhofer Inst. for Integrated Circuits IIS/EAS, Dresden, *3-5 Power Electronics GmbH, Dresden, Germany.....	81
PHYSICAL MODELING OF FERROELECTRIC TUNNEL JUNCTIONS, T. Sandu , C. Tibeica , R. Plugaru , O. Nedelcu , N. Plugaru , IMT Bucharest, Romania.....	85
THE MECHANISM OF FIELD-PLATE INDUCED THE BREAKDOWN VOLTAGE CHANGE OF HIGH VOLTAGE LDMOS, C.-K. Shih ¹ , C.-C. Liao ^{1,2} , K. Nidhi ¹ , K.-C. Kan ¹ , K.-H. Chen ² , J.-H. Lee ¹ , ¹ Vanguard International Semiconductor Corp., Hsinchu, ² National Yang Ming Chiao Tung Univ., Hsinchu, Taiwan.....	89

A MODEL OF THE V-T CHARACTERISTICS FOR AN OTFT TEMPERATURE SENSOR, R. Liguori, L. Di Benedetto, G. D. Licciardo , Univ. of Salerno, Italy.....	93
---	----

Semiconductor Devices 1

MICROTEXTURED PHOTOVOLTAIC CELLS SYSTEM FOR UAVs AUTONOMY EXTENSION, O. Ionescu^{1,2}, I.V. Cernica², E. Manea², M. Purica², C.C. Parvulescu², C. Paun², A. Popescu² , ¹ Petroleum and Gas Univ., Ploiesti, ² IMT Bucharest, Romania.....	99
DETECTING ANOMALOUS BEHAVIOR IN Si MOS CAPACITORS, R. Pascu^{1,2,3}, Gh. Pristavu², M. Kusko¹, F. Draghici², Gh. Brezeanu² , ¹ IMT Bucharest, ² Univ. "Politehnica" of Bucharest, ³ Univ. of Bucharest, Romania.....	103
COMPARATIVE STUDY BETWEEN SEMICONDUCTOR POWER DEVICES BASED ON SILICON Si, SILICON CARBIDE SiC AND GALLIUM NITRATE GaN USED IN THE ELECTRICAL SYSTEM SUBASSEMBLY OF AN ELECTRIC VEHICLE, I.C. Sburlan, I. Vasile, E. Tudor , INC DIE ICPE-CA, Bucharest, Romania.....	107
CHARACTERIZATION OF RECONFIGURABLE FETs FABRICATED ON Si EPILAYER ON SiO ₂ , S.H. Lee, S.-H. Kim, J.W. Park, T.M. Roh, S. Jung*, D. Suh , Electronics& Telecommunications Research Inst., *Advanced Inst. of Convergence Technology, Rep. of Korea....	111

Integrated Circuits

MULTI-OBJECTIVE OPTIMIZATION ALGORITHMS FOR AUTOMATED CIRCUIT SIZING OF ANALOG/ MIXED-SIGNAL CIRCUITS, M. Stănescu, C. Vișan, G. Sandu, H. Cucu, C. Diaconu*, A. Buzo*, G. Pelz* , Univ. "Politehnica" of Bucharest, *Infineon Technologies Romania, Bucharest, Romania.....	117
TCAD STUDY OF LATCH-UP SENSITIVITY TO WAFER THINNING BELOW 500 nm, G. Hiblot, K. Serbulova, G. Hellings, S.-H. Chen , IMEC, Leuven, Belgium.....	121
CHANGING THE PARADIGM IN COMMON MODE TRANSIENT IMMUNITY (CMTI) TESTING OF DUAL CHANNEL GALVANICALLY ISOLATED GATE DRIVERS, F. Vladoianu^{1,2}, M. Strelec², I. Hurez^{1,2}, V. Anghel², G. Brezeanu¹ , ¹ Univ. "Politehnica" of Bucharest, ² ON Semiconductor Romania S.R.L., Bucharest, Romania.....	125
A DUAL LOW VOLTAGE CHOPPER OFFSET-STABILIZED OPERATIONAL AMPLIFIER, C. Stănescu, C. Dinca, A. Veselu, R.A. Cojan, A. Sevcenco, V. Bricicaru, A. Croitoru , ON Semiconductor Romania S.R.L., Bucharest, Romania.....	129
MIXED-SIGNAL ADAPTIVE PRIMARY SIDE POWER CONTROL, Gh. Turcan, N.A. Braic, M. Neag, M. Topa , Technical Univ. of Cluj-Napoca, Romania.....	133
CURRENT-MODE QUADRATURE RING OSCILLATOR FOR BIOIMPEDANCE APPLICATIONS, Z. German-Sallo, R. Groza, R. Onet, M. Neag , Technical Univ. of Cluj-Napoca, Romania.....	137

Nanoscience & Nanoengineering 3 – Student Papers

- STRUCTURAL AND ELECTRICAL CHARACTERIZATION OF V_2O_3 ON VARIOUS SUBSTRATES: A COMPARATIVE STUDY, **M.T. Sultan, K. Ignatova, U.B. Arnalds**, Univ. of Iceland, Iceland..... 143
- SYNTHESIS AND PHOTOLUMINESCENCE STUDY OF SILICON NANOWIRES OBTAINED BY METAL ASSISTED CHEMICAL ETCHING, **E. Fakhri¹, M.T. Sultan², A. Manolescu¹, S. Ingvarsson², N. Plugaru³, R. Plugaru³, H.G. Svavarsson¹**, ¹Reykjavik Univ., ²Univ. of Iceland, Iceland, ³IMT Bucharest, Romania..... 147
- OPTICAL AND STRUCTURAL CHARACTERIZATION OF THIN MoS_2 LAYERS ON SiO_2/Si SUBSTRATES, TOWARDS THE DEVELOPMENT OF MoS_2/Si HETEROJUNCTION PHOTOVOLTAICS, **B. Zerbo¹, M. Modreanu², I. Povey², A. Létoublon¹, A. Rolland¹, L. Pédesseau¹, J. Even¹, B. Lépine³, P. Turban³, P. Schieffer³, A. Moréac³, O. Durand¹**, ¹Inst. FOTON-UMR 6082, France, ²Tyndall National Inst., Univ. College Cork, Ireland, ³Univ Rennes, CNRS, France..... 151
- STRUCTURAL AND COMPOSITION OF CU-DOPED $ZnTe$ THIN FILMS WITH DIFFERENT CONCENTRATIONS BY IMMERSION IN $Cu(NO_3)_2$ SOLUTION, **I. Lungu**, Moldova State Univ., Moldova..... 155

Microsensors & Modelling – Student Papers

- SUPERIOR INTERFACE TRAP VARIABILITY IMMUNITY OF HORIZONTALLY STACKED Si NANOSHEET FET IN SUB-3-nm TECHNOLOGY NODE, **A. Sudarsanan, O. Badami, K. Nayak**, Indian Inst. of Technology Hyderabad, Telangana, India..... 161
- ANALYTICAL SURFACE POTENTIAL CALCULATION FOR ORGANIC THIN-FILM TRANSISTORS, **Y.H. Zarkob, S.A. Bhat, S.A. Ahsan**, Nat. Inst. of Technology, Srinagar, India.... 165
- MicroPIV ON CARBONIC MATERIALS EMBEDDED IN A MICROFLUIDIC DEVICE, **E. Chiriac^{1,2}, B. Adiaconiță^{1,2}, C. Pachiū¹, M. Avram¹, C. Bălan²**, ¹IMT Bucharest, ²Univ. “Politehnica” of Bucharest, Romania..... 169
- TACTILE FEEDBACK THROUGH VELOSTAT AND MOTION ALGORITHM FOR A NEURAL PROSTHESIS, **M.-I. Gheorghe¹, M. Dascalu^{1,2}, F.-C. Vasiliu¹, D. Dragomir³, E. Franti^{2,3}**, ¹Univ. “Politehnica” of Bucharest, ²ICIA, Bucharest, ³IMT Bucharest, Romania..... 173

Semiconductor Devices 2 – Student Papers

- EFFECT OF INTERFACE TRAPS ON SiC -BASED POWER D-MOSFET TRANSIENT BEHAVIOUR, **S. Nayak, S. Lodha, S. Ganguly**, Indian Inst. of Tech. Bombay Mumbai, India..... 179
- ESTIMATION OF CONTACT RESISTANCE IN FOUR TERMINAL AMORPHOUS IGZO THIN FILM TRANSISTOR, **N. Firoz, S. Singh, B. Mazhari**, Indian Inst. of Technology Kanpur, India..... 183

ABNORMAL DEVICE PERFORMANCE IN TRANSFERRED MULTILAYER MoS ₂ FIELD-EFFECT TRANSISTORS, L. Tong, J. Ma, X. Chen, X. Guo, S. Gou, Y. Xia, D. Wang, H. Chen, W. Bao , Fudan Univ., Shanghai, P.R. China.....	187
PARAMETERS OPTIMIZATION FOR PIN-TUNNEL-FETs, R. Vasile¹, C. Ravariu¹, B. Appasani², A. Srinivasulu³ , ¹ Univ. “Politehnica” of Bucharest, Romania, ² Kalinga Inst. of Industrial Technology, Bhubaneswar, ³ K.R. Mangalam Univ., Haryana State, India.....	191
FABRICATION OF A ITO/PEDOT:PSS/ZnPc:I ₂ /Al SCHOTTKY DIODE SOLAR CELLS USING SOLUTION TECHNIQUE, I. Gadiac, V. Furtună, T. Potlog , Moldova State Univ., Chisinau, Moldova.....	195

Integrated Circuits – Student Papers 1

DESIGN OF 1.8V LVDS TRANSMITTER IN GF 22nm FOR ASSOCIATIVE MEMORY, Ram Teja Kothamasu, Venakata M. R. Ganda, Subhakumar R. Ankireddypalli , VEDA IIT, Hyderabad, *INVECAS, Hyderabad, India.....	201
EXPERIMENTAL COMPARISON OF 8-BIT DIGITALLY PROGRAMMABLE POTENTIOMETERS BASED ON MULTISTAGE ARCHITECTURES, G.-C. Ilie (Chiranu)^{1,2}, C. Tudoran¹, Gh. Pristavu², F. Draghici², Gh. Brezeanu² , ¹ ON Semiconductor Romania S.R.L., Bucharest, ² Univ. “Politehnica” of Bucharest, Romania.....	205
COMPARISON BETWEEN PEAK AND AN IMPROVED ONE-CYCLE CURRENT MODE CONTROL OF A BUCK CONVERTER POWER STAGE, E. Vladu, N. Braic, M. Neag, O. Pop , Technical Univ. of Cluj-Napoca, Romania.....	209
A CAPACITOR-LESS LDO WITH HIGH PSR OVER A WIDE FREQUENCY RANGE, I. Sularea, C. Răducan, M. Neag , Technical Univ. of Cluj-Napoca, Romania.....	213
STIMULI REDUNDANCY REDUCTION FOR NONLINEAR FUNCTIONAL VERIFICATION COVERAGE MODELS USING ARTIFICIAL NEURAL NETWORKS, M.-C. Cristescu, D. Ciupitu , AMIQ Consulting, Bucharest, Romania.....	217

Integrated Circuits – Student Papers 2

A NOVEL APPROACH TO THE STABILITY ANALYSIS OF CONDITIONALLY STABLE CIRCUITS, V. Belega, C.-S. Plesa, R. Onet, M. Neag , Technical Univ. of Cluj-Napoca, Romania...	223
A VERY LOW QUIESCENT CURRENT LINEAR VOLTAGE REGULATOR WITH WIDE INPUT VOLTAGE AND WIDE LOAD CURRENT RANGE FOR AUTOMOTIVE APPLICATIONS, I.-A. Ilie^{1,2}, C.Ş. Zegheru¹, A.-G. Băjenaru¹, Gh. Brezeanu² , ¹ Infineon Technologies Romania Bucharest, ² Univ. “Politehnica” of Bucharest, Romania.....	227
UTILIZING DIFFERENTIAL EVOLUTION FOR AN AUTOMATED COMPACT MODEL PARAMETER EXTRACTION, M. Huppmann, K.-W. Pieper*, A. Buzo*, L. Maurer, G. Pelz , *Univ. der Bundeswehr München, Neubiberg, *Infineon Technologies AG, Neubiberg, Germany.....	231

REVERSE POLARITY PROTECTION FOR AUTOMOTIVE NMOS LDO, P. Pop, G. Petrasuc, C.-S. Plesa, M. Neag, T. Salajan* , *Technical Univ. of Cluj-Napoca, *Infineon Technologies Romania, Bucharest, Romania.....	235
---	-----

Nanoscience & Nanoengineering 4 – Posters

UNUSUAL ELECTRONIC PROPERTIES OF THE Bi-Sb NANO- WIDTH BICRYSTAL INTERFACES, F.M. Muntyanu, V. Chistol*, E. Condrea , Inst. of Electronic Engineering and Nanotechnologies, Chisinau, *Technical Univ. of Moldova, Chisinau, Moldova.....	N/A
PHOTOCATALYTIC ACTIVITY AND STABILITY OF THE ZnO-GO COMPOSITE THIN FILMS, C. Bogatu, S. Gheorghita, D. Perniu, C. Obreja*, O. Buiu*, A. Duta , Transilvania Univ. of Brasov, *IMT Bucharest, Romania.....	245
CHEMICALLY BATH DEPOSITED Sb ₂ S ₃ FILMS AS OPTICAL PHASE CHANGE MATERIALS, C. Cobianu^{1,2}, M. Gheorghe¹, M. Modreanu³, Y. Gutierrez⁴, M. Losurdo⁴ , ¹ NANOM MEMS, Rasnov, ² Academy of Romanian Scientists, Science and Information Technology Section, Romania, ³ Tyndall National Inst., Univ. College Cork, Ireland, ⁴ Inst. of Nanotechnology, CNR-NANOTEC, Bari, Italy.....	249
MEMORY PROPERTIES OF GeZrO ₂ BASED TRILAYER STRUCTURE, C. Palade¹, A. Slav¹, M.L. Ciurea^{1,2} , *National Inst. of Materials Physics, *Academy of Romanian Scientists, Romania....	253
IMPROVING THE ON-CURRENT OF JUNCTIONLESS CARBON NANOTUBE TUNNELING FETs USING A HEAVILY n-TYPE DOPED POCKET, K. Tamersit , Dept. of Electronics and Telecommunications, Dept. of Electrical and Automatic Engineering, PIMIS Laboratory, Univ. 8 Mai 1945 Guelma, Algeria.....	257
IN-SITU MAGNETRON SPUTTERING CO-DEPOSITION OF Ge NANOPARTICLES IN Si ₃ N ₄ FILMS FOR NEAR INFRARED DETECTION, I. Stavarache¹, C. Palade¹, P. Prepelita², V.S. Teodorescu^{1,3}, M.L. Ciurea^{1,3} , ¹ National Inst. of Materials Physics, ² National Inst. for Laser, Plasma and Radiation Physics, ³ Academy of Romanian Scientists, Romania.....	261
MORPHO-STRUCTURAL AND OPTICAL CHARACTERIZATION OF SILICON NANOWIRES INTENDED FOR MICROARRAY SUBSTRATES, M.A. Popescu, I. Mihalache, C. Romanitan, M.C. Popescu*, L. Gogianu, M. Simion , IMT Bucharest, *S.C. Ronexprim S.R.L., Romania.....	265
PLA NANOCOMPOSITES WITH ANTIMICROBIAL ACTION, BASED ON OLIVE FRUIT POLYPHENOLS AND CITRUS FRUIT EXTRACTS ENCAPSULATED IN MALTODEXTRIN, I.V. Tudose¹, I. Rosca², C. Romanitan³, O.N. Ionescu³, K. Petrotos⁴, S. Zoutsos⁵, M.P. Sucheai^{1,3}, E. Koudoumas¹ , ¹ Hellenic Mediterranean Univ., Greece, ² "Petru Poni" Inst. of Macromolecular Chemistry, Iasi, ³ IMT Bucharest, Romania, ⁴ Dept. of Agriculture-Agrotechnology, Univ. of Thessaly, Greece, ⁵ Dept. of Energy Systems, School of Technology, Univ. of Thessaly, Greece.....	269

Microsensors & Devices – Posters

- MEASUREMENT SETUP AND PROCEDURE FOR THE ACCURATE DETERMINATION OF THE GAIN AND THE BREAKDOWN VOLTAGE FOR SILICON PHOTOMULTIPLIER (SiPM) ARRAYS, **F.-A. Popescu, G. Chiritoi, E.M. Popescu**, Inst. of Space Science, Romania..... 275
- DARK CURRENT AND NOISE IN DIFFUSED AND EPITAXIAL InAs PHOTODIODES, **A. Tkachuk, V. Tetyorkin*, A. Sukach***, V. Vynnychenko Central Ukrainian State Pedagogical Univ., *V.Ye. Lashkaryov Inst. of Physics of Semiconductors of NAS of Ukraine, Ukraine..... 279
- ELECTROCHEMICAL CHARACTERIZATION AND APPLICATION OF A GOLD MICROFABRICATED DEVICE, **L.A. Dinu Gugoasa, A.M. Baracu, G. Craciun**, IMT Bucharest, Romania..... 283
- THE EFFECT OF TEMPERATURE ON THE ELECTRICAL RESPONSE EXCITED BY ACOUSTICALLY DRIVEN BANDGAP MODULATION IN AN INDIUM ANTIMONIDE TRANSDUCER, **H. Salehi Najafabadi, M.A. Meier, G.A. Hallock***, Univ. of Houston, Houston, TX, *Univ. of Texas at Austin, TX, USA..... 287
- DOUBLE-GATE JUNCTIONLESS GNR-FETs OPERATING IN THE BTBT REGIME: A SIMPLE DESIGN WITH IMPROVED PERFORMANCE FOR LOW-POWER APPLICATIONS, **K. Tamersit**, Dept. of Electronics and Telecommunications, Dept. of Electrical and Automatic Engineering, PIMIS Laboratory, Univ. 8 Mai 1945, Guelma, Algeria..... 291
- TESTING AND CHARACTERIZATION OF A BIOSENSOR FOR THE DETECTION OF INFECTIONS IN TISSUE BASED ON Rh6G AND AuNP FUNCTIONALIZED WITH BSA, **L. Draghiciu, C. Parvulescu, G. Craciun, C. Voitincu, A. Albu, C. Romanitan**, IMT Bucharest, Romania..... 295
- INVESTIGATING ELECTRICAL CHARACTERISTICS OF CYLINDRICAL NANOSCALE VERTICAL VACUUM CHANNEL FIELD EMISSION TRANSISTOR WITH DIFFERENT CATHODE MATERIALS, **F. Kohani Khoshkbijari, M.J. Sharifi**, Shahid Beheshti Univ., Tehran, Iran..... 299

Workshop “Harvesting of energy with nanomaterials” organized by NANO EH -H2020-EIC-FETPROACT project

- DESIGN OF DRAs FOR ALL-SILICON EFFICIENT MILLIMETER-WAVE ENERGY HARVESTERS, **S. Trovarello, D. Masotti, A. Costanzo**, Univ. of Bologna, Italy..... 305